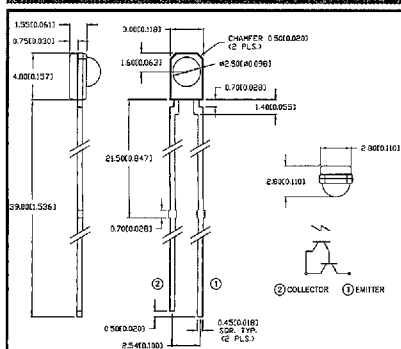


discrete sensors photodarlington transistors



SIDE LOOKING PACKAGES

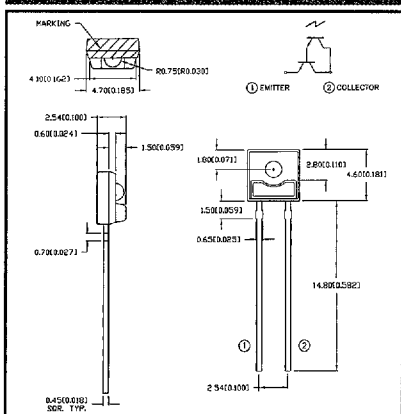
OED-PT-304R2



Package Style	Lens	Limits of Safe Operation			ICEO @ 10 V _{CEO} (nA) Max
		V _{CEO} (V) Max	PC (mW) Max	t-opr (°C)	
Side Looking Leaded	Black Resin	30	75	-20 ~ + 85	1000

I _c (mA) @ EV ~ 1000 Lx				λ _p (nm) Typ	Δ θ deg Typ	λ (nm)	tr/τf @ V _{EC} 5V I _c 1mA
Min	Typ	Max	V _{CE} (V)				
5.0	—	—	5.0	850	±40	500 ~ 1000	65/75 μS

OED-PT-23G

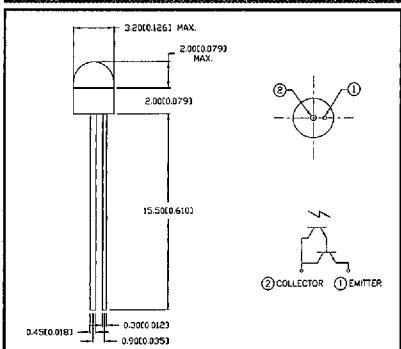


Package Style	Lens	Limits of Safe Operation			ICEO @ 10 V _{CEO} (nA) Max
		V _{CEO} (V) Max	PC (mW) Max	t-opr (°C)	
Side Looking Leaded	Clear Resin	30	150	-20 ~ + 100	1000

I _c (mA) @ EV ~ 1000 Lx				λ _p (nm) Typ	Δ θ deg Typ	λ (nm)	tr/τf @ V _{EC} 5V I _c 1mA
Min	Typ	Max	V _{CE} (V)				
5.0	—	—	5.0	800	±30	480 ~ 1000	65/75 μS

RADIAL LEADED, EPOXY LENS PACKAGES

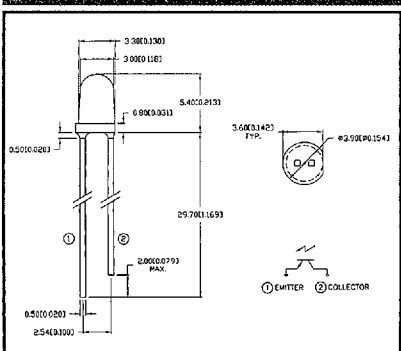
OED-PT-1CL3



Package Style	Lens	Limits of Safe Operation			ICEO @ 10 V _{CEO} (nA) Max
		V _{CEO} (V) Max	PC (mW) Max	t-opr (°C)	
T-3mm Ceramic Stem	Clear Resin	20	100	-25 ~ + 85	100

I _c (mA) @ EV ~ 1000 Lx				λ _p (nm) Typ	Δ θ deg Typ	λ (nm)	tr/τf @ V _{EC} 5V I _c 1mA
Min	Typ	Max	V _{CE} (V)				
5.0	—	—	5.0	800	±50	480 ~ 1000	65/75 μS

OED-PT-8L



Package Style	Lens	Limits of Safe Operation			ICEO @ 10 V _{CEO} (nA) Max
		V _{CEO} (V) Max	PC (mW) Max	t-opr (°C)	
T-3mm Leaded	Clear Resin	20	100	-20 ~ + 80	1000

I _c (mA) @ EV ~ 1000 Lx				λ _p (nm) Typ	Δ θ deg Typ	λ (nm)	tr/τf @ V _{EC} 5V I _c 1mA
Min	Typ	Max	V _{CE} (V)				
5.0	—	—	5.0	800	±20	480 ~ 1000	40/60 μS